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AMD Xilinx - XC2S50-6TQG144C Datasheet



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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	384
Number of Logic Elements/Cells	1728
Total RAM Bits	32768
Number of I/O	92
Number of Gates	50000
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	144-LQFP
Supplier Device Package	144-TQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xc2s50-6tqg144c

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

DS001-1 (v2.8) June 13, 2008

Spartan-II FPGA Family: Introduction and Ordering Information

Product Specification

Introduction

The Spartan[®]-II Field-Programmable Gate Array family gives users high performance, abundant logic resources, and a rich feature set, all at an exceptionally low price. The six-member family offers densities ranging from 15,000 to 200,000 system gates, as shown in Table 1. System performance is supported up to 200 MHz. Features include block RAM (to 56K bits), distributed RAM (to 75,264 bits), 16 selectable I/O standards, and four DLLs. Fast, predictable interconnect means that successive design iterations continue to meet timing requirements.

The Spartan-II family is a superior alternative to mask-programmed ASICs. The FPGA avoids the initial cost, lengthy development cycles, and inherent risk of conventional ASICs. Also, FPGA programmability permits design upgrades in the field with no hardware replacement necessary (impossible with ASICs).

Features

- Second generation ASIC replacement technology
 - Densities as high as 5,292 logic cells with up to 200,000 system gates
 - Streamlined features based on Virtex[®] FPGA architecture
 - Unlimited reprogrammability
 - Very low cost
 - Cost-effective 0.18 micron process

- System level features
 - SelectRAM[™] hierarchical memory:
 - · 16 bits/LUT distributed RAM
 - Configurable 4K bit block RAM
 - Fast interfaces to external RAM
 - Fully PCI compliant
 - Low-power segmented routing architecture
 - Full readback ability for verification/observability
 - Dedicated carry logic for high-speed arithmetic
 - Efficient multiplier support
 - Cascade chain for wide-input functions
 - Abundant registers/latches with enable, set, reset
 - Four dedicated DLLs for advanced clock control
 - Four primary low-skew global clock distribution nets
 - IEEE 1149.1 compatible boundary scan logic
- Versatile I/O and packaging
 - Pb-free package options
 - Low-cost packages available in all densities
 - Family footprint compatibility in common packages
 - 16 high-performance interface standards
 - Hot swap Compact PCI friendly
 - Zero hold time simplifies system timing
- Core logic powered at 2.5V and I/Os powered at 1.5V, 2.5V, or 3.3V
- Fully supported by powerful Xilinx[®] ISE[®] development system
 - Fully automatic mapping, placement, and routing

Table 1: Spartan-II FPGA Family Members							
Device	Logic Cells	System Gates (Logic and RAM)	CLB Array (R x C)	Total CLBs	Maximum Available User I/O ⁽¹⁾	Total Distributed RAM Bits	Total Block RAM Bits
XC2S15	432	15,000	8 x 12	96	86	6,144	16K
XC2S30	972	30,000	12 x 18	216	92	13,824	24K
XC2S50	1,728	50,000	16 x 24	384	176	24,576	32K
XC2S100	2,700	100,000	20 x 30	600	176	38,400	40K
XC2S150	3,888	150,000	24 x 36	864	260	55,296	48K
XC2S200	5,292	200,000	28 x 42	1,176	284	75,264	56K

Notes:

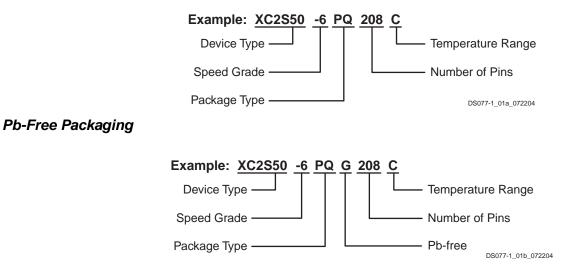
1. All user I/O counts do not include the four global clock/user input pins. See details in Table 2, page 4.

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Ordering Information

Spartan-II devices are available in both standard and Pb-free packaging options for all device/package combinations. The Pb-free packages include a special "G" character in the ordering code.

Standard Packaging



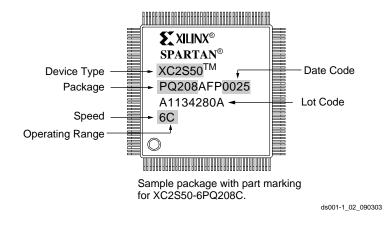
Device Ordering Options

Device		Speed Grade	Number of Pins / Package Type		Temperatur	re Range (T _J)
XC2S15	-5	Standard Performance	VQ(G)100	100-pin Plastic Very Thin QFP	C = Commercial	0°C to +85°C
XC2S30	-6	Higher Performance ⁽¹⁾	CS(G)144	144-ball Chip-Scale BGA	I = Industrial	-40°C to +100°C
XC2S50			TQ(G)144	144-pin Plastic Thin QFP		1
XC2S100			PQ(G)208	208-pin Plastic QFP		
XC2S150			FG(G)256	256-ball Fine Pitch BGA		
XC2S200			FG(G)456	456-ball Fine Pitch BGA		

Notes:

1. The -6 speed grade is exclusively available in the Commercial temperature range.

Device Part Marking



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Revision History

Date	Version No.	Description
09/18/00	2.0	Sectioned the Spartan-II Family data sheet into four modules. Added industrial temperature range information.
10/31/00	2.1	Removed Power down feature.
03/05/01	2.2	Added statement on PROMs.
11/01/01	2.3	Updated Product Availability chart. Minor text edits.
09/03/03	2.4	Added device part marking.
08/02/04	2.5	Added information on Pb-free packaging options and removed discontinued options.
06/13/08	2.8	Updated description and links. Updated all modules for continuous page, figure, and table numbering. Synchronized all modules to v2.8.

DS001-2 (v2.8) June 13, 2008

Architectural Description

Spartan-II FPGA Array

The Spartan[®]-II field-programmable gate array, shown in Figure 2, is composed of five major configurable elements:

- IOBs provide the interface between the package pins and the internal logic
- CLBs provide the functional elements for constructing most logic
- Dedicated block RAM memories of 4096 bits each
- Clock DLLs for clock-distribution delay compensation and clock domain control
- Versatile multi-level interconnect structure

As can be seen in Figure 2, the CLBs form the central logic structure with easy access to all support and routing structures. The IOBs are located around all the logic and

Spartan-II FPGA Family: Functional Description

Product Specification

memory elements for easy and quick routing of signals on and off the chip.

Values stored in static memory cells control all the configurable logic elements and interconnect resources. These values load into the memory cells on power-up, and can reload if necessary to change the function of the device.

Each of these elements will be discussed in detail in the following sections.

Input/Output Block

The Spartan-II FPGA IOB, as seen in Figure 2, features inputs and outputs that support a wide variety of I/O signaling standards. These high-speed inputs and outputs are capable of supporting various state of the art memory and bus interfaces. Table 3 lists several of the standards which are supported along with the required reference, output and termination voltages needed to meet the standard.

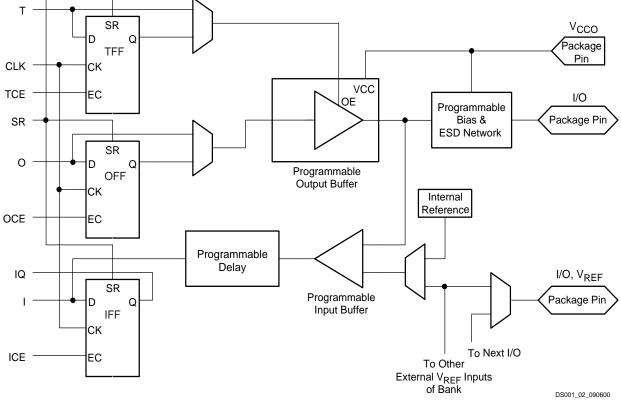


Figure 2: Spartan-II FPGA Input/Output Block (IOB)

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Boundary-scan operation is independent of individual IOB configurations, and unaffected by package type. All IOBs, including unbonded ones, are treated as independent 3-state bidirectional pins in a single scan chain. Retention of the bidirectional test capability after configuration facilitates the testing of external interconnections.

Table 7 lists the boundary-scan instructions supported in Spartan-II FPGAs. Internal signals can be captured during EXTEST by connecting them to unbonded or unused IOBs. They may also be connected to the unused outputs of IOBs defined as unidirectional input pins.

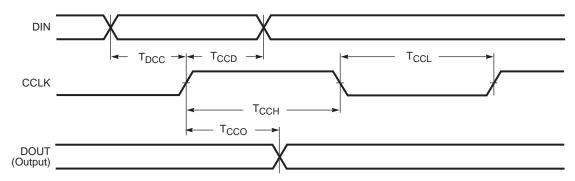
Boundary-Scan Command	Binary Code[4:0]	Description
EXTEST	00000	Enables boundary-scan EXTEST operation
SAMPLE	00001	Enables boundary-scan SAMPLE operation
USR1	00010	Access user-defined register 1
USR2	00011	Access user-defined register 2
CFG_OUT	00100	Access the configuration bus for Readback
CFG_IN	00101	Access the configuration bus for Configuration
INTEST	00111	Enables boundary-scan INTEST operation
USRCODE	01000	Enables shifting out USER code
IDCODE	01001	Enables shifting out of ID Code
HIZ	01010	Disables output pins while enabling the Bypass Register
JSTART	01100	Clock the start-up sequence when StartupClk is TCK
BYPASS	11111	Enables BYPASS
RESERVED	All other codes	Xilinx [®] reserved instructions

Table 7: Boundary-Scan Instructions

The public boundary-scan instructions are available prior to configuration. After configuration, the public instructions remain available together with any USERCODE instructions installed during the configuration. While the SAMPLE and BYPASS instructions are available during configuration, it is recommended that boundary-scan operations not be performed during this transitional period.

In addition to the test instructions outlined above, the boundary-scan circuitry can be used to configure the FPGA, and also to read back the configuration data.

To facilitate internal scan chains, the User Register provides three outputs (Reset, Update, and Shift) that represent the corresponding states in the boundary-scan internal state machine.



DS001_16_032300

Symbol		Description		Units
T _{DCC}		DIN setup	5	ns, min
T _{CCD}	CCLK	DIN hold	0	ns, min
T _{CCO}		DOUT	12	ns, max
ТССН		High time	5	ns, min
T _{CCL}		Low time	5	ns, min
F _{CC}		Maximum frequency	66	MHz, max

Figure 16: Slave Serial Mode Timing

BUFGDLL Pin Descriptions

Use the BUFGDLL macro as the simplest way to provide zero propagation delay for a high-fanout on-chip clock from an external input. This macro uses the IBUFG, CLKDLL and BUFG primitives to implement the most basic DLL application as shown in Figure 25.

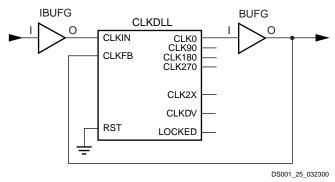


Figure 25: BUFGDLL Block Diagram

This macro does not provide access to the advanced clock domain controls or to the clock multiplication or clock division features of the DLL. This macro also does not provide access to the RST or LOCKED pins of the DLL. For access to these features, a designer must use the DLL primitives described in the following sections.

Source Clock Input — I

The I pin provides the user source clock, the clock signal on which the DLL operates, to the BUFGDLL. For the BUFGDLL macro the source clock frequency must fall in the low frequency range as specified in the data sheet. The BUFGDLL requires an external signal source clock. Therefore, only an external input port can source the signal that drives the BUFGDLL I pin.

Clock Output — O

The clock output pin O represents a delay-compensated version of the source clock (I) signal. This signal, sourced by a global clock buffer BUFG primitive, takes advantage of the dedicated global clock routing resources of the device.

The output clock has a 50/50 duty cycle unless you deactivate the duty cycle correction property.

CLKDLL Primitive Pin Descriptions

The library CLKDLL primitives provide access to the complete set of DLL features needed when implementing more complex applications with the DLL.

Source Clock Input — CLKIN

The CLKIN pin provides the user source clock (the clock signal on which the DLL operates) to the DLL. The CLKIN frequency must fall in the ranges specified in the data sheet. A global clock buffer (BUFG) driven from another CLKDLL

or one of the global clock input buffers (IBUFG) on the same edge of the device (top or bottom) must source this clock signal.

Feedback Clock Input — CLKFB

The DLL requires a reference or feedback signal to provide the delay-compensated output. Connect only the CLK0 or CLK2X DLL outputs to the feedback clock input (CLKFB) pin to provide the necessary feedback to the DLL. Either a global clock buffer (BUFG) or one of the global clock input buffers (IBUFG) on the same edge of the device (top or bottom) must source this clock signal.

If an IBUFG sources the CLKFB pin, the following special rules apply.

- 1. An external input port must source the signal that drives the IBUFG I pin.
- The CLK2X output must feed back to the device if both the CLK0 and CLK2X outputs are driving off chip devices.
- 3. That signal must directly drive only OBUFs and nothing else.

These rules enable the software to determine which DLL clock output sources the CLKFB pin.

Reset Input — RST

When the reset pin RST activates, the LOCKED signal deactivates within four source clock cycles. The RST pin, active High, must either connect to a dynamic signal or be tied to ground. As the DLL delay taps reset to zero, glitches can occur on the DLL clock output pins. Activation of the RST pin can also severely affect the duty cycle of the clock output pins. Furthermore, the DLL output clocks no longer deskew with respect to one another. The DLL must be reset when the input clock frequency changes, if the device is reconfigured in Boundary-Scan mode, if the device undergoes a hot swap, and after the device is configured if the input clock is not stable during the startup sequence.

2x Clock Output — CLK2X

The output pin CLK2X provides a frequency-doubled clock with an automatic 50/50 duty-cycle correction. Until the CLKDLL has achieved lock, the CLK2X output appears as a 1x version of the input clock with a 25/75 duty cycle. This behavior allows the DLL to lock on the correct edge with respect to source clock. This pin is not available on the CLKDLLHF primitive.

Clock Divide Output — CLKDV

The clock divide output pin CLKDV provides a lower frequency version of the source clock. The CLKDV_DIVIDE property controls CLKDV such that the source clock is divided by N where N is either 1.5, 2, 2.5, 3, 4, 5, 8, or 16.

This feature provides automatic duty cycle correction. The CLKDV output pin has a 50/50 duty cycle for all values of the

At the third rising edge of CLKA, the T_{BCCS} parameter is violated with two writes to memory location 0x0F. The DOA and DOB busses reflect the contents of the DIA and DIB busses, but the stored value at 0x7E is invalid.

At the fourth rising edge of CLKA, a read operation is performed at memory location 0x0F and invalid data is present on the DOA bus. Port B also executes a read operation to memory location 0x0F and also reads invalid data.

At the fifth rising edge of CLKA a read operation is performed that does not violate the T_{BCCS} parameter to the previous write of 0x7E by Port B. THe DOA bus reflects the recently written value by Port B.

Initialization

The block RAM memory can initialize during the device configuration sequence. The 16 initialization properties of 64 hex values each (a total of 4096 bits) set the initialization of each RAM. These properties appear in Table 14. Any initialization properties not explicitly set configure as zeros. Partial initialization strings pad with zeros. Initialization strings greater than 64 hex values generate an error. The RAMs can be simulated with the initialization values using generics in VHDL simulators and parameters in Verilog simulators.

Initialization in VHDL

The block RAM structures may be initialized in VHDL for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the VHDL code uses a generic to pass the initialization.

Initialization in Verilog

The block RAM structures may be initialized in Verilog for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the Verilog code uses a defparam to pass the initialization.

Block Memory Generation

The CORE Generator[™] software generates memory structures using the block RAM features. This program outputs VHDL or Verilog simulation code templates and an EDIF file for inclusion in a design.

Property	Memory Cells
INIT_00	255 to 0
INIT_01	511 to 256
INIT_02	767 to 512
INIT_03	1023 to 768
INIT_04	1279 to 1024

Property	Memory Cells
INIT_05	1535 to 1280
INIT_06	1791 to 1536
INIT_07	2047 to 1792
INIT_08	2303 to 2048
INIT_09	2559 to 2304
INIT_0a	2815 to 2560
INIT_0b	3071 to 2816
INIT_0c	3327 to 3072
INIT_0d	3583 to 3328
INIT_0e	3839 to 3584
INIT_0f	4095 to 3840

For design examples and more information on using the Block RAM, see <u>XAPP173</u>, Using Block SelectRAM+ Memory in Spartan-II FPGAs.

Using Versatile I/O

The Spartan-II FPGA family includes a highly configurable, high-performance I/O resource called Versatile I/O to provide support for a wide variety of I/O standards. The Versatile I/O resource is a robust set of features including programmable control of output drive strength, slew rate, and input delay and hold time. Taking advantage of the flexibility and Versatile I/O features and the design considerations described in this document can improve and simplify system level design.

Introduction

As FPGAs continue to grow in size and capacity, the larger and more complex systems designed for them demand an increased variety of I/O standards. Furthermore, as system clock speeds continue to increase, the need for high-performance I/O becomes more important. While chip-to-chip delays have an increasingly substantial impact on overall system speed, the task of achieving the desired system performance becomes more difficult with the proliferation of low-voltage I/O standards. Versatile I/O, the revolutionary input/output resources of Spartan-II devices, has resolved this potential problem by providing a highly configurable, high-performance alternative to the I/O resources of more conventional programmable devices. The Spartan-II FPGA Versatile I/O features combine the flexibility and time-to-market advantages of programmable logic with the high performance previously available only with ASICs and custom ICs.

Each Versatile I/O block can support up to 16 I/O standards. Supporting such a variety of I/O standards allows the

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GTL

A sample circuit illustrating a valid termination technique for GTL is shown in Figure 42. Table 20 lists DC voltage specifications for the GTL standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics.



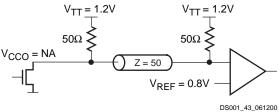


Figure 42: Terminated GTL

Table 20: GTL Voltage Specifications

Parameter	Min	Тур	Max
V _{CCO}	-	N/A	-
$V_{REF} = N \times V_{TT}^{(1)}$	0.74	0.8	0.86
V _{TT}	1.14	1.2	1.26
$V_{IH} \ge V_{REF} + 0.05$	0.79	0.85	-
$V_{IL} \leq V_{REF} - 0.05$	-	0.75	0.81
V _{OH}	-	-	-
V _{OL}	-	0.2	0.4
I _{OH} at V _{OH} (mA)	-	-	-
I _{OL} at V _{OL} (mA) at 0.4V	32	-	-
I_{OL} at V_{OL} (mA) at 0.2V	-	-	40

Notes:

1. N must be greater than or equal to 0.653 and less than or equal to 0.68.

GTL+

A sample circuit illustrating a valid termination technique for GTL+ appears in Figure 43. DC voltage specifications appear in Table 21 for the GTL+ standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics.

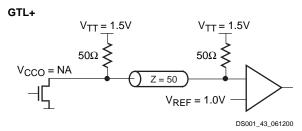


Figure 43: Terminated GTL+

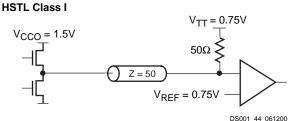
Table 21: GTL+ Voltage Specifications

Parameter	Min	Тур	Max
V _{CCO}	-	-	-
$V_{REF} = N \times V_{TT}^{(1)}$	0.88	1.0	1.12
V _{TT}	1.35	1.5	1.65
$V_{IH} \ge V_{REF} + 0.1$	0.98	1.1	-
$V_{IL} \le V_{REF} - 0.1$	-	0.9	1.02
V _{OH}	-	-	-
V _{OL}	0.3	0.45	0.6
I _{OH} at V _{OH} (mA)	-	-	-
I _{OL} at V _{OL} (mA) at 0.6V	36	-	-
I_{OL} at V_{OL} (mA) at 0.3V	-	-	48

Notes:

HSTL Class I

A sample circuit illustrating a valid termination technique for HSTL_I appears in Figure 44. DC voltage specifications appear in Table 22 for the HSTL_1 standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics.



DS001_44_061.

Figure 44: Terminated HSTL Class I

Table 22: HSTL Class I Voltage Specification

Parameter	Min	Тур	Max
V _{CCO}	1.40	1.50	1.60
V _{REF}	0.68	0.75	0.90
V _{TT}	-	$V_{CCO} imes 0.5$	-
V _{IH}	V _{REF} + 0.1	-	-
V _{IL}	-	-	$V_{REF} - 0.1$
V _{OH}	$V_{CCO} - 0.4$	-	-
V _{OL}			0.4
I _{OH} at V _{OH} (mA)	-8	-	-
I _{OL} at V _{OL} (mA)	8	-	-

^{1.} N must be greater than or equal to 0.653 and less than or equal to 0.68.

SSTL2_I

A sample circuit illustrating a valid termination technique for SSTL2_I appears in Figure 49. DC voltage specifications appear in Table 27 for the SSTL2_I standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics

SSTL2 Class I

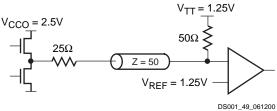


Figure 49: Terminated SSTL2 Class I

Table	27:	SSTL2_I	Voltage	Specifications
-------	-----	---------	---------	----------------

Parameter	Min	Тур	Max
V _{CCO}	2.3	2.5	2.7
$V_{REF} = 0.5 \times V_{CCO}$	1.15	1.25	1.35
$V_{TT} = V_{REF} + N^{(1)}$	1.11	1.25	1.39
$V_{IH} \ge V_{REF} + 0.18$	1.33	1.43	3.0 ⁽²⁾
$V_{IL} \leq V_{REF} - 0.18$	-0.3 ⁽³⁾	1.07	1.17
V _{OH} ≥ V _{REF} + 0.61	1.76	-	-
$V_{OL} \leq V_{REF} - 0.61$	-	-	0.74
I _{OH} at V _{OH} (mA)	-7.6	-	-
I _{OL} at V _{OL} (mA)	7.6	-	-

Notes:

- 1. N must be greater than or equal to -0.04 and less than or equal to 0.04.
- 2. V_{IH} maximum is V_{CCO} + 0.3.
- 3. V_{IL} minimum does not conform to the formula.

SSTL2 Class II

A sample circuit illustrating a valid termination technique for SSTL2_II appears in Figure 50. DC voltage specifications appear in Table 28 for the SSTL2_II standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics.

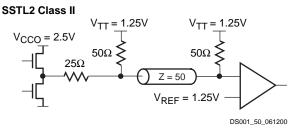


Figure 50: Terminated SSTL2 Class II

Table 28: SSTL2_II Voltage Specifications

Parameter	Min	Тур	Max
V _{CCO}	2.3	2.5	2.7
$V_{REF} = 0.5 \times V_{CCO}$	1.15	1.25	1.35
$V_{TT} = V_{REF} + N^{(1)}$	1.11	1.25	1.39
$V_{IH} \ge V_{REF} + 0.18$	1.33	1.43	3.0 ⁽²⁾
$V_{IL} \leq V_{REF} - 0.18$	-0.3 ⁽³⁾	1.07	1.17
$V_{OH} \ge V_{REF} + 0.8$	1.95	-	-
$V_{OL} \leq V_{REF} - 0.8$	-	-	0.55
I _{OH} at V _{OH} (mA)	-15.2	-	-
I _{OL} at V _{OL} (mA)	15.2	-	-

Notes:

- 1. N must be greater than or equal to -0.04 and less than or equal to 0.04.
- 2. V_{IH} maximum is V_{CCO} + 0.3.
- 3. V_{IL} minimum does not conform to the formula.



Spartan-II FPGA Family: DC and Switching Characteristics

DS001-3 (v2.8) June 13, 2008

Product Specification

Definition of Terms

In this document, some specifications may be designated as Advance or Preliminary. These terms are defined as follows:

Advance: Initial estimates based on simulation and/or extrapolation from other speed grades, devices, or families. Values are subject to change. Use as estimates, not for production.

Preliminary: Based on preliminary characterization. Further changes are not expected.

Unmarked: Specifications not identified as either Advance or Preliminary are to be considered Final.

Except for pin-to-pin input and output parameters, the AC parameter delay specifications included in this document are derived from measuring internal test patterns. All limits are representative of worst-case supply voltage and junction temperature conditions. Typical numbers are based on measurements taken at a nominal V_{CCINT} level of 2.5V and a junction temperature of 25°C. The parameters included are common to popular designs and typical applications. All specifications are subject to change without notice.

DC Specifications

Absolute Maximum Ratings⁽¹⁾

Symbol	Descriptio	Description		Max	Units
V _{CCINT}	Supply voltage relative to GND ⁽²⁾		-0.5	3.0	V
V _{CCO}	Supply voltage relative to GND ⁽²⁾		-0.5	4.0	V
V _{REF}	Input reference voltage	Input reference voltage		3.6	V
V _{IN}	Input voltage relative to GND ⁽³⁾	5V tolerant I/O ⁽⁴⁾	-0.5	5.5	V
		No 5V tolerance ⁽⁵⁾	-0.5	V _{CCO} +0.5	V
V _{TS}	Voltage applied to 3-state output	5V tolerant I/O ⁽⁴⁾	-0.5	5.5	V
		No 5V tolerance ⁽⁵⁾	-0.5	V _{CCO} +0.5	V
T _{STG}	Storage temperature (ambient)		-65	+150	°C
TJ	Junction temperature	Junction temperature		+125	°C

Notes:

1. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those listed under Operating Conditions is not implied. Exposure to Absolute Maximum Ratings conditions for extended periods of time may affect device reliability.

2. Power supplies may turn on in any order.

3. V_{IN} should not exceed V_{CCO} by more than 3.6V over extended periods of time (e.g., longer than a day).

4. Spartan[®]-II device I/Os are 5V Tolerant whenever the LVTTL, LVCMOS2, or PCI33_5 signal standard has been selected. With 5V Tolerant I/Os selected, the Maximum DC overshoot must be limited to either +5.5V or 10 mA, and undershoot must be limited to either -0.5V or 10 mA, whichever is easier to achieve. The Maximum AC conditions are as follows: The device pins may undershoot to -2.0V or overshoot to +7.0V, provided this over/undershoot lasts no more than 11 ns with a forcing current no greater than 100 mA.

5. Without 5V Tolerant I/Os selected, the Maximum DC overshoot must be limited to either V_{CCO} + 0.5V or 10 mA, and undershoot must be limited to -0.5V or 10 mA, whichever is easier to achieve. The Maximum AC conditions are as follows: The device pins may undershoot to -2.0V or overshoot to V_{CCO} + 2.0V, provided this over/undershoot lasts no more than 11 ns with a forcing current no greater than 100 mA.

6. For soldering guidelines, see the <u>Packaging Information</u> on the Xilinx[®] web site.

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Input/Output		V _{IL}	V	н	V _{OL}	V _{OH}	I _{OL}	I _{ОН}
Standard	V, Min	V, Max	V, Min	V, Max	V, Max	V, Min	mA	mA
CTT	-0.5	V _{REF} – 0.2	V _{REF} + 0.2	3.6	V _{REF} – 0.4	V _{REF} + 0.4	8	-8
AGP	-0.5	V _{REF} – 0.2	V _{REF} + 0.2	3.6	10% V _{CCO}	90% V _{CCO}	Note (2)	Note (2)

Notes:

1. V_{OL} and V_{OH} for lower drive currents are sample tested.

2. Tested according to the relevant specifications.

Switching Characteristics

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values. For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer (TRCE in the Xilinx Development System) and back-annotated to the simulation netlist. All timing parameters assume worst-case operating conditions (supply voltage and junction temperature). Values apply to all Spartan-II devices unless otherwise noted.

Global Clock Input to Output Delay for LVTTL, with DLL (Pin-to-Pin)⁽¹⁾

			S	Speed Grade		
			All	-6	-5	
Symbol	Description	Device	Min	Max	Max	Units
T _{ICKOFDLL}	Global clock input to output delay using output flip-flop for LVTTL, 12 mA, fast slew rate, <i>with</i> DLL.	All		2.9	3.3	ns

Notes:

1. Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.

- Output timing is measured at 1.4V with 35 pF external capacitive load for LVTTL. The 35 pF load does not apply to the Min values. For other I/O standards and different loads, see the tables "Constants for Calculating TIOOP" and "Delay Measurement Methodology," page 60.
- 3. DLL output jitter is already included in the timing calculation.
- 4. For data *output* with different standards, adjust delays with the values shown in "IOB Output Delay Adjustments for Different Standards," page 59. For a global clock input with standards other than LVTTL, adjust delays with values from the "I/O Standard Global Clock Input Adjustments," page 61.

Global Clock Input to Output Delay for LVTTL, *without* DLL (Pin-to-Pin)⁽¹⁾

				Speed Grade		
			All	-6	-5	-
Symbol	Description	Device	Min	Max	Max	Units
T _{ICKOF}	Global clock input to output delay	XC2S15		4.5	5.4	ns
	using output flip-flop for LVTTL, 12 mA, fast slew rate, <i>without</i> DLL.	XC2S30		4.5	5.4	ns
		XC2S50		4.5	5.4	ns
		XC2S100		4.6	5.5	ns
		XC2S150		4.6	5.5	ns
		XC2S200		4.7	5.6	ns

Notes:

1. Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.

 Output timing is measured at 1.4V with 35 pF external capacitive load for LVTTL. The 35 pF load does not apply to the Min values. For other I/O standards and different loads, see the tables "Constants for Calculating TIOOP" and "Delay Measurement Methodology," page 60.

 For data *output* with different standards, adjust delays with the values shown in "IOB Output Delay Adjustments for Different Standards," page 59. For a global clock input with standards other than LVTTL, adjust delays with values from the "I/O Standard Global Clock Input Adjustments," page 61.



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Spartan-II FPGA Family: Pinout Tables

Product Specification

Introduction

This section describes how the various pins on a Spartan[®]-II FPGA connect within the supported component packages, and provides device-specific thermal characteristics. Spartan-II FPGAs are available in both standard and Pb-free, RoHS versions of each package, with the Pb-free version adding a "G" to the middle of the package code. Except for the thermal characteristics, all

information for the standard package applies equally to the Pb-free package.

Pin Types

Most pins on a Spartan-II FPGA are general-purpose, user-defined I/O pins. There are, however, different functional types of pins on Spartan-II FPGA packages, as outlined in Table 35.

Table 35: Pin Definitions

Pin Name	Dedicated	Direction	Description
GCK0, GCK1, GCK2, GCK3	No	Input	Clock input pins that connect to Global Clock Buffers. These pins become user inputs when not needed for clocks.
M0, M1, M2	Yes	Input	Mode pins are used to specify the configuration mode.
CCLK	Yes	Input or Output	The configuration Clock I/O pin. It is an input for slave-parallel and slave-serial modes, and output in master-serial mode.
PROGRAM	Yes	Input	Initiates a configuration sequence when asserted Low.
DONE	Yes	Bidirectional	Indicates that configuration loading is complete, and that the start-up sequence is in progress. The output may be open drain.
INIT	No	Bidirectional (Open-drain)	When Low, indicates that the configuration memory is being cleared. This pin becomes a user I/O after configuration.
BUSY/DOUT	No	Output	In Slave Parallel mode, BUSY controls the rate at which configuration data is loaded. This pin becomes a user I/O after configuration unless the Slave Parallel port is retained.
			In serial modes, DOUT provides configuration data to downstream devices in a daisy-chain. This pin becomes a user I/O after configuration.
D0/DIN, D1, D2, D3, D4, D5, D6, D7	No	Input or Output	In Slave Parallel mode, D0-D7 are configuration data input pins. During readback, D0-D7 are output pins. These pins become user I/Os after configuration unless the Slave Parallel port is retained.
			In serial modes, DIN is the single data input. This pin becomes a user I/O after configuration.
WRITE	No	Input	In Slave Parallel mode, the active-low Write Enable signal. This pin becomes a user I/O after configuration unless the Slave Parallel port is retained.
CS	No	Input	In Slave Parallel mode, the active-low Chip Select signal. This pin becomes a user I/O after configuration unless the Slave Parallel port is retained.
TDI, TDO, TMS, TCK	Yes	Mixed	Boundary Scan Test Access Port pins (IEEE 1149.1).
V _{CCINT}	Yes	Input	Power supply pins for the internal core logic.
V _{CCO}	Yes	Input	Power supply pins for output drivers (subject to banking rules)
V _{REF}	No	Input	Input threshold voltage pins. Become user I/Os when an external threshold voltage is not needed (subject to banking rules).
GND	Yes	Input	Ground.
IRDY, TRDY	No	See PCI core documentation	These signals can only be accessed when using Xilinx [®] PCI cores. If the cores are not used, these pins are available as user I/Os.

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Package	Leads	Туре	Maximum I/O	Lead Pitch (mm)	Footprint Area (mm)	Height (mm)	Mass ⁽¹⁾ (g)
VQ100 / VQG100	100	Very Thin Quad Flat Pack (VQFP)	60	0.5	16 x 16	1.20	0.6
TQ144 / TQG144	144	Thin Quad Flat Pack (TQFP)	92	0.5	22 x 22	1.60	1.4
CS144 / CSG144	144	Chip Scale Ball Grid Array (CSBGA)	92	0.8	12 x 12	1.20	0.3
PQ208 / PQG208	208	Plastic Quad Flat Pack (PQFP)	140	0.5	30.6 x 30.6	3.70	5.3
FG256 / FGG256	256	Fine-pitch Ball Grid Array (FBGA)	176	1.0	17 x 17	2.00	0.9
FG456 / FGG456	456	Fine-pitch Ball Grid Array (FBGA)	284	1.0	23 x 23	2.60	2.2

Table 36: Spartan-II Family Package Options

Notes:

1. Package mass is $\pm 10\%$.

Note: Some early versions of Spartan-II devices, including the XC2S15 and XC2S30 ES devices and the XC2S150 with date code 0045 or earlier, included a power-down pin. For more information, see <u>Answer Record 10500</u>.

VCCO Banks

Some of the I/O standards require specific V_{CCO} voltages. These voltages are externally connected to device pins that serve groups of IOBs, called banks. Eight I/O banks result from separating each edge of the FPGA into two banks (see Figure 3 in Module 2). Each bank has multiple V_{CCO} pins which must be connected to the same voltage. In the smaller packages, the V_{CCO} pins are connected between banks, effectively reducing the number of independent banks available (see Table 37). These interconnected banks are shown in the Pinout Tables with V_{CCO} pads for multiple banks connected to the same pin.

Table 37: Independent VCCO Banks Available

Package	VQ100	CS144	FG256
	PQ208	TQ144	FG456
Independent Banks	1	4	8

Package Overview

Table 36 shows the six low-cost, space-saving productionpackage styles for the Spartan-II family.

Each package style is available in an environmentally friendly lead-free (Pb-free) option. The Pb-free packages include an extra 'G' in the package style name. For example, the standard "CS144" package becomes "CSG144" when ordered as the Pb-free option. Leaded (non-Pb-free) packages may be available for selected devices, with the same pin-out and without the "G" in the ordering code; contact Xilinx sales for more information. The mechanical dimensions of the standard and Pb-free packages are similar, as shown in the mechanical drawings provided in Table 38. For additional package information, see <u>UG112</u>: *Device Package User Guide*.

Mechanical Drawings

Detailed mechanical drawings for each package type are available from the Xilinx web site at the specified location in Table 38.

Material Declaration Data Sheets (MDDS) are also available on the <u>Xilinx web site</u> for each package.

Table 38: Xilinx Package Documentation

Package	Drawing	MDDS
VQ100	Package Drawing	PK173_VQ100
VQG100		PK130_VQG100
TQ144	Package Drawing	PK169_TQ144
TQG144		PK126_TQG144
CS144	Package Drawing	PK149_CS144
CSG144	_	PK103_CSG144
PQ208	Package Drawing	PK166_PQ208
PQG208	_	PK123_PQG208
FG256	Package Drawing	PK151_FG256
FGG256		PK105_FGG256
FG456	Package Drawing	PK154_FG456
FGG456		PK109_FGG456

Pinout Tables

The following device-specific pinout tables include all packages available for each Spartan[®]-II device. They follow the pad locations around the die, and include Boundary Scan register locations.

XC2S15 Device Pinouts

XC2S15 Pad Name					Bndry
Function	Bank	VQ100	TQ144	CS144	Scan
GND	-	P1	P143	A1	-
TMS	-	P2	P142	B1	-
I/O	7	P3	P141	C2	77
I/O	7	-	P140	C1	80
I/O, V _{REF}	7	P4	P139	D4	83
I/O	7	P5	P137	D2	86
I/O	7	P6	P136	D1	89
GND	-	-	P135	E4	-
I/O	7	P7	P134	E3	92
I/O	7	-	P133	E2	95
I/O, V _{REF}	7	P8	P132	E1	98
I/O	7	P9	P131	F4	101
I/O	7	-	P130	F3	104
I/O, IRDY ⁽¹⁾	7	P10	P129	F2	107
GND	-	P11	P128	F1	-
V _{CCO}	7	P12	P127	G2	-
V _{CCO}	6	P12	P127	G2	-
I/O, TRDY ⁽¹⁾	6	P13	P126	G1	110
V _{CCINT}	-	P14	P125	G3	-
I/O	6	-	P124	G4	113
I/O	6	P15	P123	H1	116
I/O, V _{REF}	6	P16	P122	H2	119
I/O	6	-	P121	H3	122
I/O	6	P17	P120	H4	125
GND	-	-	P119	J1	-
I/O	6	P18	P118	J2	128
I/O	6	P19	P117	J3	131
I/O, V _{REF}	6	P20	P115	K1	134
I/O	6	-	P114	K2	137
I/O	6	P21	P113	K3	140
I/O	6	P22	P112	L1	143
M1	-	P23	P111	L2	146
GND	-	P24	P110	L3	-
M0	-	P25	P109	M1	147
V _{CCO}	6	P26	P108	M2	-
V _{CCO}	5	P26	P107	N1	-

XC2S15 Device Pinouts (Continued)

XC2S15 Pad Name					Bndry
Function	Bank	VQ100	TQ144	CS144	Scan
M2	-	P27	P106	N2	148
I/O	5	-	P103	K4	155
I/O, V _{REF}	5	P30	P102	L4	158
I/O	5	P31	P100	N4	161
I/O	5	P32	P99	K5	164
GND	-	-	P98	L5	-
V _{CCINT}	-	P33	P97	M5	-
I/O	5	-	P96	N5	167
I/O	5	-	P95	K6	170
I/O, V _{REF}	5	P34	P94	L6	173
I/O	5	-	P93	M6	176
V _{CCINT}	-	P35	P92	N6	-
I, GCK1	5	P36	P91	M7	185
V _{CCO}	5	P37	P90	N7	-
V _{CCO}	4	P37	P90	N7	-
GND	-	P38	P89	L7	-
I, GCK0	4	P39	P88	K7	186
I/O	4	P40	P87	N8	190
I/O	4	-	P86	M8	193
I/O, V _{REF}	4	P41	P85	L8	196
I/O	4	-	P84	K8	199
I/O	4	-	P83	N9	202
V _{CCINT}	-	P42	P82	M9	-
GND	-	-	P81	L9	-
I/O	4	P43	P80	K9	205
I/O	4	P44	P79	N10	208
I/O, V _{REF}	4	P45	P77	L10	211
I/O	4	-	P76	N11	214
I/O	4	P46	P75	M11	217
I/O	4	P47	P74	L11	220
GND	-	P48	P73	N12	-
DONE	3	P49	P72	M12	223
V _{cco}	4	P50	P71	N13	-
V _{CCO}	3	P50	P70	M13	-
PROGRAM	-	P51	P69	L12	226
I/O (INIT)	3	P52	P68	L13	227
I/O (D7)	3	P53	P67	K10	230
I/O	3	-	P66	K11	233
I/O, V _{REF}	3	P54	P65	K12	236
I/O	3	P55	P63	J10	239
I/O (D6)	3	P56	P62	J11	233
"O (DO)	5	1.00	102	011	272

Bndry

Scan

203

206

209

212

215

218

-

219

-

-

220

227

230

233

236

239

242

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245

248

251

254

257

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260

263

266

-

275

-

-

-

276

280

283

286

289

-

292

XC2S30 Device Pinouts

XC2S30 Device Pinouts	(Continued)
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(C2330 D												
XC2S30 Pad	Name					Bndry	XC2S30 Pad	Name				
Function	Bank	VQ100	TQ144	CS144	PQ208	Scan	Function	Bank	VQ100	TQ144	CS144	ŀ
GND	-	P1	P143	A1	P1	-	I/O, V _{REF}	6	P20	P115	K1	
TMS	-	P2	P142	B1	P2	-	I/O	6	-	-	-	
I/O	7	P3	P141	C2	P3	113	I/O	6	-	P114	K2	
I/O	7	-	P140	C1	P4	116	I/O	6	P21	P113	K3	
I/O	7	-	-	-	P5	119	I/O	6	P22	P112	L1	
I/O, V _{REF}	7	P4	P139	D4	P6	122	M1	-	P23	P111	L2	
I/O	7	-	P138	D3	P8	125	GND	-	P24	P110	L3	
I/O	7	P5	P137	D2	P9	128	MO	-	P25	P109	M1	
I/O	7	P6	P136	D1	P10	131	V _{CCO}	6	P26	P108	M2	
GND	-	-	P135	E4	P11	-	V _{CCO}	5	P26	P107	N1	
V _{CCO}	7	-	-	-	P12	-	M2	-	P27	P106	N2	
1/0	7	P7	P134	E3	P14	134	I/O	5	-	P103	K4	
I/O	7	-	P133	E2	P15	137	I/O	5	-	-	-	
I/O	7	-	-	-	P16	140	I/O, V _{REF}	5	P30	P102	L4	
I/O	7	-	-	-	P17	143	I/O	5	-	P101	M4	
I/O	7	-	-	-	P18	146	I/O	5	P31	P100	N4	
GND	-	-	-	-	P19	-	I/O	5	P32	P99	K5	
I/O, V _{REF}	7	P8	P132	E1	P20	149	GND	-	-	P98	L5	
I/O	7	P9	P131	F4	P21	152	V _{CCO}	5	-	-	-	
I/O	7	-	P130	F3	P22	155	V _{CCINT}	-	P33	P97	M5	
I/O	7	-	-	-	P23	158	I/O	5	-	P96	N5	
I/O, IRDY ⁽¹⁾	7	P10	P129	F2	P24	161	I/O	5	-	P95	K6	
GND	-	P11	P128	F1	P25	-	I/O	5	-	-	-	
V _{CCO}	7	P12	P127	G2	P26	-	I/O	5	-	-	-	
V _{CCO}	6	P12	P127	G2	P26	-	I/O	5	-	-	-	
I/O, TRDY ⁽¹⁾	6	P13	P126	G1	P27	164	GND	-	-	-	-	
V _{CCINT}	-	P14	P125	G3	P28	-	I/O, V _{REF}	5	P34	P94	L6	
I/O	6	-	P124	G4	P29	170	I/O	5	-	-	-	
I/O	6	P15	P123	H1	P30	173	I/O	5	-	P93	M6	
I/O, V _{REF}	6	P16	P122	H2	P31	176	V _{CCINT}	-	P35	P92	N6	
GND	-	-	-	-	P32	-	I, GCK1	5	P36	P91	M7	
I/O	6	-	-	-	P33	179	V _{CCO}	5	P37	P90	N7	
I/O	6	-	-	-	P34	182	V _{CCO}	4	P37	P90	N7	
I/O	6	-	-	-	P35	185	GND	-	P38	P89	L7	
I/O	6	-	P121	H3	P36	188	I, GCK0	4	P39	P88	K7	
I/O	6	P17	P120	H4	P37	191	I/O	4	P40	P87	N8	
V _{CCO}	6	-	-	-	P39	-	I/O	4	-	P86	M8	
GND	-	-	P119	J1	P40	-	I/O	4	-	-	-	
I/O	6	P18	P118	J2	P41	194	I/O, V _{REF}	4	P41	P85	L8	
I/O	6	P19	P117	J3	P42	197	GND	-	-	-	-	
I/O	6	-	P116	J4	P43	200	I/O	4	-	-	-	

XC2S100 Device Pinouts (Continued)

XC2S100 Pad Name						Bndry
Function	Bank	TQ144	PQ208	FG256	FG456	Scan
I/O	2	-	-	F12	G20	695
I/O	2	-	P149	E15	F19	701
I/O, V _{REF}	2	P41	P150	F13	F21	704
V _{CCO}	2	-	-	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	-	-	GND*	GND*	-
I/O	2	-	P151	E14	F20	707
I/O	2	-	-	C16	F18	710
I/O	2	-	-	-	E21	713
I/O	2	P40	P152	E13	D22	716
I/O	2	-	-	B16	E20	719
I/O (DIN, D0)	2	P39	P153	D14	D20	725
I/O (DOUT, BUSY)	2	P38	P154	C15	C21	728
CCLK	2	P37	P155	D15	B22	731
V _{CCO}	2	P36	P156	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
V _{CCO}	1	P35	P156	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
TDO	2	P34	P157	B14	A21	-
GND	-	P33	P158	GND*	GND*	-
TDI	-	P32	P159	A15	B20	-
I/O (CS)	1	P31	P160	B13	C19	0
I/O (WRITE)	1	P30	P161	C13	A20	3
I/O	1	-	-	C12	D17	9
I/O	1	P29	P162	A14	A19	12
I/O	1	-	-	-	B18	15
I/O	1	-	-	D12	C17	18
I/O	1	-	P163	B12	D16	21
GND	-	-	-	GND*	GND*	-
V _{CCO}	1	-	-	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
I/O, V _{REF}	1	P28	P164	C11	A18	24
I/O	1	-	P165	A13	B17	27
I/O	1	-	-	D11	D15	33
I/O	1	-	P166	A12	C16	36
I/O	1	-	-	-	D14	39
I/O, V _{REF}	1	P27	P167	E11	E14	42
I/O	1	P26	P168	B11	A16	45
GND	-	P25	P169	GND*	GND*	-

XC2S100 Device Pinouts (Continued)

XC2S100 Pad Name						Bndry
Function	Function Bank		PQ208	FG256	FG456	Scan
V _{CCO}	1	-	P170	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
V _{CCINT}	-	P24	P171	V _{CCINT} *	V _{CCINT} *	-
I/O	1	P23	P172	A11	C15	48
I/O	1	P22	P173	C10	B15	51
I/O	1	-	-	-	F12	54
I/O	1	-	P174	B10	C14	57
I/O	1	-	P175	D10	D13	63
I/O	1	-	P176	A10	C13	66
GND	-	-	P177	GND*	GND*	-
I/O, V _{REF}	1	P21	P178	B9	B13	69
I/O	1	-	P179	E10	E12	72
I/O	1	-	-	A9	B12	75
I/O	1	P20	P180	D9	D12	78
I/O	1	P19	P181	A8	D11	84
I, GCK2	1	P18	P182	C9	A11	90
GND	-	P17	P183	GND*	GND*	-
V _{CCO}	1	P16	P184	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
V _{CCO}	0	P16	P184	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-
I, GCK3	0	P15	P185	B8	C11	91
V _{CCINT}	-	P14	P186	V _{CCINT} *	V_{CCINT}^{*}	-
I/O	0	P13	P187	A7	A10	101
I/O	0	-	-	D8	B10	104

XC2S150 Device Pinouts (Continued)

XC2S150 Pad Name					Pndry
Function	Function Bank		FG256	FG456	Bndry Scan
I/O	6	P46	P1	T4	404
I/O	6	-	L5	W1	407
I/O	6	-	-	V2	410
I/O	6	-	-	U4	413
I/O	6	P47	N2	Y1	416
GND	-	-	GND*	GND*	-
I/O	6	-	M4	W2	419
I/O	6	-	-	V3	422
I/O	6	-	-	V4	425
I/O	6	P48	R1	Y2	428
I/O	6	P49	M3	W3	431
M1	-	P50	P2	U5	434
GND	-	P51	GND*	GND*	-
MO	-	P52	N3	AB2	435
V _{CCO}	6	P53	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
V _{CCO}	5	P53	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
M2	-	P54	R3	Y4	436
I/O	5	-	-	W5	443
I/O	5	-	-	AB3	446
I/O	5	-	N5	V7	449
GND	-	-	GND*	GND*	-
I/O	5	P57	T2	Y6	452
I/O	5	-	-	AA4	455
I/O	5	-	-	AB4	458
I/O	5	-	P5	W6	461
I/O	5	P58	Т3	Y7	464
GND	-	-	GND*	GND*	-
V _{CCO}	5	-	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
I/O, V _{REF}	5	P59	T4	AA5	467
I/O	5	P60	M6	AB5	470
I/O	5	-	-	V8	473
I/O	5	-	-	AA6	476
I/O	5	-	T5	AB6	479
I/O	5	P61	N6	AA7	482
I/O	5	-	-	W7	485
I/O, V _{REF}	5	P62	R5	W8	488
I/O	5	P63	P6	Y8	491
GND	-	P64	GND*	GND*	-

XC2S150 Device Pinouts (Continued)

XC2S150 Pad Name					Bndry
Function	Bank	PQ208	FG256	FG456	Scan
V _{CCO}	5	P65	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
V _{CCINT}	-	P66	V _{CCINT} *	V _{CCINT} *	-
I/O	5	P67	R6	AA8	494
I/O	5	P68	M7	V9	497
I/O	5	-	-	W9	503
I/O	5	-	-	AB9	506
I/O	5	P69	N7	Y9	509
I/O	5	-	-	V10	512
I/O	5	P70	T6	W10	518
I/O	5	P71	P7	AB10	521
GND	-	P72	GND*	GND*	-
V _{CCO}	5	-	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
I/O, V _{REF}	5	P73	P8	Y10	524
I/O	5	P74	R7	V11	527
I/O	5	-	T7	W11	530
I/O	5	P75	Т8	AB11	533
I/O	5	-	-	U11	536
V _{CCINT}	-	P76	V _{CCINT} *	V _{CCINT} *	-
I, GCK1	5	P77	R8	Y11	545
V _{CCO}	5	P78	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
V _{CCO}	4	P78	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	P79	GND*	GND*	-
I, GCK0	4	P80	N8	W12	546
I/O	4	P81	N9	U12	550
I/O	4	-	-	V12	553
I/O	4	P82	R9	Y12	556
I/O	4	-	N10	AA12	559
I/O	4	P83	Т9	AB13	562
I/O, V _{REF}	4	P84	P9	AA13	565
V _{CCO}	4	-	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	P85	GND*	GND*	-
I/O	4	P86	M10	Y13	568
I/O	4	P87	R10	V13	571
I/O	4	-	-	W14	577
I/O	4	P88	P10	AA14	580
I/O	4	-	-	V14	583
I/O	4	-	-	Y14	586
I/O	4	P89	T10	AB15	592

XC2S200 Device Pinouts

XC2S200 Pa	d Name				Bndry
Function	Bank	PQ208	FG256	FG456	Scan
GND	-	P1	GND*	GND*	-
TMS	-	P2	D3	D3	-
I/O	7	P3	C2	B1	257
I/O	7	-	-	E4	263
I/O	7	-	-	C1	266
I/O	7	-	A2	F5	269
GND	-	-	GND*	GND*	-
I/O, V _{REF}	7	P4	B1	D2	272
I/O	7	-	-	E3	275
I/O	7	-	-	F4	281
GND	-	-	GND*	GND*	-
I/O	7	-	E3	G5	284
I/O	7	P5	D2	F3	287
GND	-	-	GND*	GND*	-
V _{CCO}	7	-	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
I/O, V _{REF}	7	P6	C1	E2	290
I/O	7	P7	F3	E1	293
I/O	7	-	-	G4	296
I/O	7	-	-	G3	299
I/O	7	-	E2	H5	302
GND	-	-	GND*	GND*	-
I/O	7	P8	E4	F2	305
I/O	7	-	-	F1	308
I/O, V _{REF}	7	P9	D1	H4	314
I/O	7	P10	E1	G1	317
GND	-	P11	GND*	GND*	-
V _{CCO}	7	P12	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
V _{CCINT}	-	P13	V _{CCINT} *	V _{CCINT} *	-
I/O	7	P14	F2	H3	320
I/O	7	P15	G3	H2	323
I/O	7	-	-	J4	326
I/O	7	-	-	H1	329
I/O	7	-	F1	J5	332
GND	-	-	GND*	GND*	-
I/O	7	P16	F4	J2	335
I/O	7	-	-	J3	338
I/O	7	-	-	J1	341
I/O	7	P17	F5	K5	344
I/O	7	P18	G2	K1	347
GND	-	P19	GND*	GND*	-

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name			-		Bndry
Function	Bank	PQ208	FG256	FG456	Scan
V _{CCO}	7	-	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
I/O, V _{REF}	7	P20	H3	K3	350
I/O	7	P21	G4	K4	353
I/O	7	-	-	K2	359
I/O	7	-	H2	L6	362
I/O	7	P22	G5	L1	365
I/O	7	-	-	L5	368
I/O	7	P23	H4	L4	374
I/O, IRDY ⁽¹⁾	7	P24	G1	L3	377
GND	-	P25	GND*	GND*	-
V _{CCO}	7	P26	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
V _{CCO}	6	P26	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
I/O, TRDY ⁽¹⁾	6	P27	J2	M1	380
V _{CCINT}	-	P28	V _{CCINT} *	V _{CCINT} *	-
I/O	6	-	-	M6	389
I/O	6	P29	H1	M3	392
I/O	6	-	J4	M4	395
I/O	6	-	-	N1	398
I/O	6	P30	J1	M5	404
I/O, V _{REF}	6	P31	J3	N2	407
V _{CCO}	6	-	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
GND	-	P32	GND*	GND*	-
I/O	6	P33	K5	N3	410
I/O	6	P34	K2	N4	413
I/O	6	-	-	P1	416
I/O	6	-	-	N5	419
I/O	6	P35	K1	P2	422
GND	-	-	GND*	GND*	-
I/O	6	-	K3	P4	425
I/O	6	-	-	R1	428
I/O	6	-	-	P5	431
I/O	6	P36	L1	P3	434
I/O	6	P37	L2	R2	437
V _{CCINT}	-	P38	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	6	P39	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
GND	-	P40	GND*	GND*	-
I/O	6	P41	K4	T1	440
I/O, V _{REF}	6	P42	M1	R4	443

XC2S200 Device Pinouts (Continued)

XC2S200 Pad				Bndry	
Function	Bank	PQ208	FG256	FG456	Scan
V _{CCO}	1	P156	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
TDO	2	P157	B14	A21	-
GND	-	P158	GND*	GND*	-
TDI	-	P159	A15	B20	-
I/O (<u>CS</u>)	1	P160	B13	C19	0
I/O (WRITE)	1	P161	C13	A20	3
I/O	1	-	-	B19	9
I/O	1	-	-	C18	12
I/O	1	-	C12	D17	15
GND	-	-	GND*	GND*	-
I/O, V _{REF}	1	P162	A14	A19	18
I/O	1	-	-	B18	21
I/O	1	-	-	E16	27
I/O	1	-	D12	C17	30
I/O	1	P163	B12	D16	33
GND	-	-	GND*	GND*	-
V _{CCO}	1	-	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
I/O, V _{REF}	1	P164	C11	A18	36
I/O	1	P165	A13	B17	39
I/O	1	-	-	E15	42
I/O	1	-	-	A17	45
I/O	1	-	D11	D15	48
GND	-	-	GND*	GND*	-
I/O	1	P166	A12	C16	51
I/O	1	-	-	D14	54
I/O, V _{REF}	1	P167	E11	E14	60
I/O	1	P168	B11	A16	63
GND	-	P169	GND*	GND*	-
V _{CCO}	1	P170	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
V _{CCINT}	-	P171	V _{CCINT} *	V _{CCINT} *	-
I/O	1	P172	A11	C15	66
I/O	1	P173	C10	B15	69
I/O	1	-	-	E13	72
I/O	1	-	-	A15	75
I/O	1	-	-	F12	78
GND	-	-	GND*	GND*	-
I/O	1	P174	B10	C14	81
I/O	1	-	-	B14	84
I/O	1	-	-	A14	87

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name					Bndry
Function	Bank	PQ208	FG256	FG456	Scan
I/O	1	P175	D10	D13	90
I/O	1	P176	A10	C13	93
GND	-	P177	GND*	GND*	-
V _{CCO}	1	-	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
I/O, V _{REF}	1	P178	B9	B13	96
I/O	1	P179	E10	E12	99
I/O	1	-	-	A13	105
I/O	1	-	A9	B12	108
I/O	1	P180	D9	D12	111
I/O	1	-	-	C12	114
I/O	1	P181	A8	D11	120
I, GCK2	1	P182	C9	A11	126
GND	-	P183	GND*	GND*	-
V _{CCO}	1	P184	V _{CCO} Bank 1*	V _{CCO} Bank 1*	-
V _{CCO}	0	P184	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-
I, GCK3	0	P185	B8	C11	127
V _{CCINT}	-	P186	V _{CCINT} *	V _{CCINT} *	-
I/O	0	-	-	E11	137
I/O	0	P187	A7	A10	140
I/O	0	-	D8	B10	143
I/O	0	-	-	F11	146
I/O	0	P188	A6	C10	152
I/O, V _{REF}	0	P189	B7	A9	155
V _{CCO}	0	-	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-
GND	-	P190	GND*	GND*	-
I/O	0	P191	C8	B9	158
I/O	0	P192	D7	E10	161
I/O	0	-	-	C9	164
I/O	0	-	-	D10	167
I/O	0	P193	E7	A8	170
GND	-	-	GND*	GND*	-
I/O	0	-	-	D9	173
I/O	0	-	-	B8	176
I/O	0	-	-	C8	179
I/O	0	P194	C7	E9	182
I/O	0	P195	B6	A7	185
V _{CCINT}	-	P196	V _{CCINT} *	V_{CCINT}^{*}	-
V _{CCO}	0	P197	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-